

## EYP-ECL-0780-00080-1500-BFW01-0005

Revision 0.70

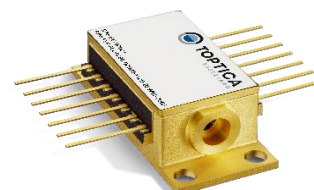
2022-04-14

# SINGLE FREQUENCY LASER DIODES

## mini ECDL Laser

## General Product Information

Product	Application
780 nm mini-ECDL Laser	Spectroscopy (Rb D2 line)
with hermetic 14-Pin Butterfly Housing (RoHS compliant)	Metrology
including Monitor Diode, Thermoelectric Cooler and Thermistor	
with integrated Beam Collimation	



## Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	$T_S$	°C	-40		85
Operational Temperature at Case	$T_C$	°C	-40		85
Operational Temperature at Laser Chip	$T_{LD}$	°C	0		50
Forward Current	$I_F$	mA			200
Reverse Voltage	$V_R$	V			2
Output Power	$P_{opt}$	mW			100
TEC Current	$I_{TEC}$	A			1.1
TEC Voltage	$V_{TEC}$	V			2.8

## Measurement Conditions / Comments

Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

## Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	$T_{case}$	°C	-20		65
Operational Temperature at Laser Chip	$T_{LD}$	°C	5		45
Forward Current	$I_F$	mA			180
Output Power	$P_{opt}$	mW	20		80

## Measurement Conditions / Comments

measured by integrated Thermistor

Characteristics at  $T_{LD} = 25^\circ \text{C}$  at BOL

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	$\lambda_C$	nm	779	780	781
Target Wavelength	$\lambda_T$	nm		780.24	
Linewidth (FWHM)	$\Delta\lambda$	kHz		200	400
Mode-hop free Tuning Range	$\Delta\lambda_{tune}$	pm		25	
Sidemode Suppression Ratio	SMSR	dB	30	50	
Temperature Coefficient of Wavelength	$d\lambda / dT$	nm / K		0.008	
Current Coefficient of Wavelength	$d\lambda / dI$	nm / mA		0.001	

## Measurement Conditions / Comments

reached within  $T_{LD} - 5^\circ \dots 45^\circ \text{C}$

By current tuning, at target wavelength

$P_{opt} = 80 \text{ mW}$

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Characteristics at  $T_{LD} = 25^{\circ}\text{C}$  at BOL

cont'd

Parameter	Symbol	Unit	min	typ	max
Laser Current @ $P_{opt} = 80\text{ mW}$	$I_{LD}$	mA			180
Slope Efficiency	$\eta$	W / A	0.6	0.8	1
Threshold Current	$I_{th}$	mA			70
Divergence parallel (FWHM)	$\Theta_{  }$	mrاد		2	
Divergence perpendicular (FWHM)	$\Theta_{\perp}$	mrاد		2	
Beam Diameter horizontal	$d_{  }$	mm		1.0	1.2
Beam Diameter vertical	$d_{\perp}$	mm		0.8	1.2
Degree of Polarization	DOP	%		90	

## Measurement Conditions / Comments

Threshold current may drift, no violation of the max. Va  
parallel to the base plate of the housing (see p. 3)  
perpendicular to base plate of the housing (see p. 3)  
parallel to the base plate of the housing (see p. 3)  
perpendicular to base plate of the housing (see p. 3)  
 $P_{opt} = 80\text{ mW}$ ; E field perpendicular to the base plate

## Monitor Diode

Parameter	Symbol	Unit	min	typ	max
Monitor Detector Responsivity	$I_{mon} / P_{opt}$	$\mu\text{A/mW}$	10		400

## Measurement Conditions / Comments

 $U_R = 5\text{ V}$ 

## Thermoelectric Cooler

Parameter	Symbol	Unit	min	typ	max
Current	$I_{TEC}$	A		0.4	
Voltage	$U_{TEC}$	V		1.3	
Power Dissipation (total loss at case)	$P_{loss}$	W		0.5	
Temperature Difference	$\Delta T$	K			50

## Measurement Conditions / Comments

 $P_{opt} = 80\text{ mW}$ ,  $\Delta T = 20\text{ K}$  $P_{opt} = 80\text{ mW}$ ,  $\Delta T = 20\text{ K}$  $P_{opt} = 80\text{ mW}$ ,  $\Delta T = 20\text{ K}$  $P_{opt} = 80\text{ mW}$ ,  $\Delta T = |T_{case} - T_{LD}|$ 

## Thermistor (Standard NTC Type)

Parameter	Symbol	Unit	min	typ	max
Resistance	R	k $\Omega$		10	
Beta Coefficient	$\beta$			3892	
Steinhart & Hart Coefficient A	A			$1.1293 \times 10^{-3}$	
Steinhart & Hart Coefficient B	B			$2.3410 \times 10^{-4}$	
Steinhart & Hart Coefficient C	C			$8.7755 \times 10^{-8}$	

## Measurement Conditions / Comments

 $T_{LD} = 25^{\circ}\text{C}$  $R_1 / R_2 = e^{\beta(1/T_1 - 1/T_2)}$  at  $T_{LD} = 0^{\circ} \dots 50^{\circ}\text{C}$  $1/T = A + B(\ln R) + C(\ln R)^3$ 

T: temperature in Kelvin

R: resistance at T in Ohm

## Ordering Information:



800 Village Walk #316  
Guilford, CT 06437  
Ph: 203-401-8093

Email orders to: [sales@xsoptix.com](mailto:sales@xsoptix.com)  
Fax orders to: 800-878-7282

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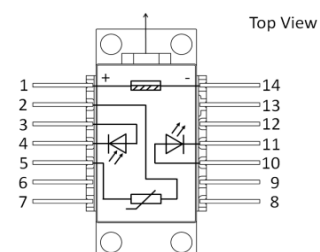
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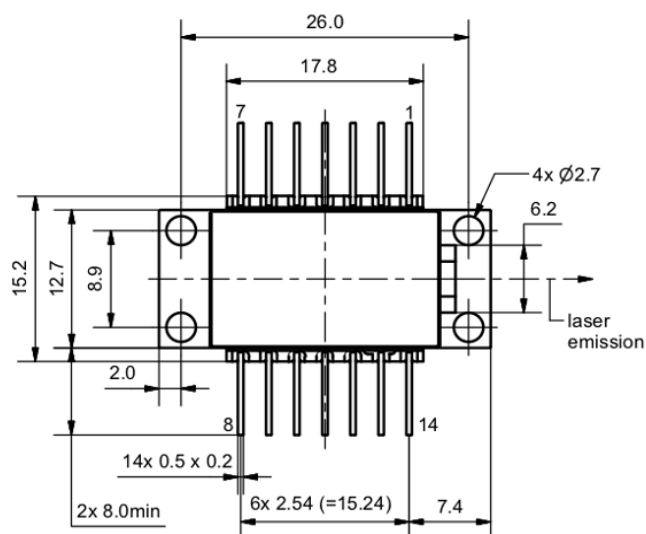
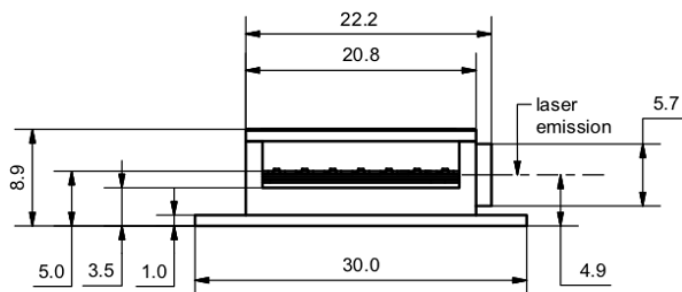
## SINGLE FREQUENCY LASER DIODES mini ECDL Laser

### Pin Assignment

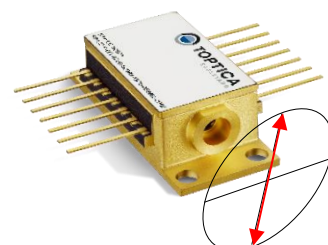
1	Thermoelectric Cooler (+)	14	Thermoelectric Cooler (-)
2	Thermistor	13	Case
3	Photodiode (Anode)	12	not connected
4	Photodiode (Cathode)	11	Laser Diode (Cathode)
5	Thermistor	10	Laser Diode (Anode)
6	not connected	9	not connected
7	not connected	8	not connected



### Package Drawings



AIZ-15-0729-0947



E field perpendicular to base plate

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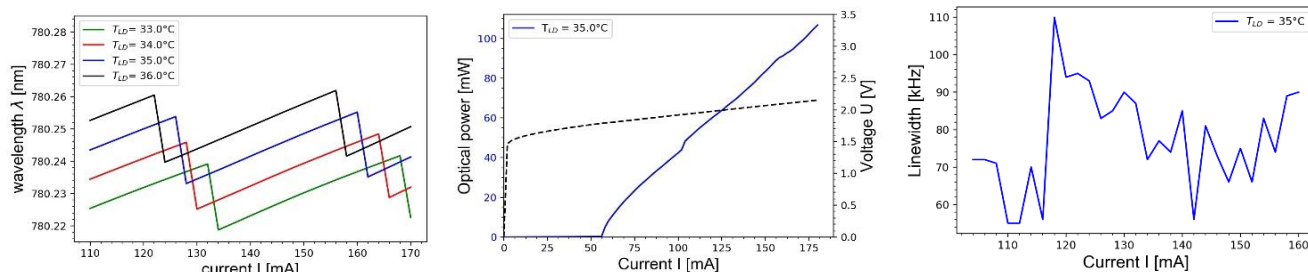
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# SINGLE FREQUENCY LASER DIODES

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### Typical Measurement Results



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

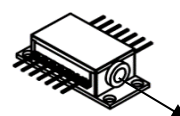
### Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.

The DFB laser is sensitive against optical feedback, so an optical isolator may be required in order to avoid any disturbance of the emission spectrum. Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode.

Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

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Laser Emission



INVISIBLE LASER RADIATION  
AVOID EYE OR SKIN EXPOSURE  
TO DIRECT OR SCATTERED RADIATION  
**CLASS 4 LASER PRODUCT**  
WAVELENGTH 780 nm  
MAX. OUTPUT POWER 100 mW

IEC-60825-1



**DANGER**  
INVISIBLE LASER RADIATION  
AVOID EYE OR SKIN EXPOSURE TO  
DIRECT OR SCATTERED RADIATION  
GaAs SEMICONDUCTOR LASER DIODE  
10 mW MAX OUTPUT AT 780 nm

Complies with 21 CFR 1040.10 and 1040.40